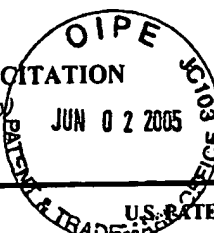


ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

| Title of Invention | FINFET WITH LOW GATE CAPACITANCE AND LOW EXTRINSIC RESISTANCE | | | | | | |
|---|---|-------------|------------|-----------------|------|-------|----------|
| Application Number : 10/711,170 | | | | | | | |
| Confirmation Number: | | | | | | | |
| First Named Applicant: Brent Anderson | | | | | | | |
| Attorney Docket Number: BUR920040040US1 | | | | | | | |
| Art Unit: 2818 | | | | | | | |
| Examiner: HOANG-QUAN HO | | | | | | | |
| Search string: (6660596 or 6635923 or 6118161 or 20030178670 or 20030151077).pn | | | | | | | |
| US Patent Documents | | | | | | | |
| Note: Applicant is not required to submit a paper copy of cited US Patent Documents | | | | | | | |
| init | Cite.No. | Patent No. | Date | Patentee | Kind | Class | Subclass |
| 101 | 1 | 6660596 | 2003-12-09 | Adkisson, et al | | 438 | 286 |
| 102 | 2 | 6635923 | 2003-10-21 | Hanafi, et al | | 257 | 327 |
| 103 | 3 | 6118161 | 2000-09-12 | Chapman, et al | | 257 | 401 |
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| Note: Applicant is not required to submit a paper copy of cited US Published Applications | | | | | | | |
| init | Cite.No. | Pub. No. | Date | Applicant | Kind | Class | Subclass |
| 101 | 1 | 20030178670 | 2003-09-25 | Fried, et al | | 257 | 315 |
| 102 | 2 | 20030151077 | 2003-08-14 | Mathew, et al | | 257 | 250 |
| Signature | | | | | | | |
| Examiner Name | | | | Date | | | |
| HOANG-QUAN HO | | | | 9/15/2005 | | | |

| INFORMATION DISCLOSURE CITATION (Use several sheets if necessary) | | | | Docket Number (Optional) BUR920040040US1 | | Application Number 10/7/11/70 | | |
|---|-----|---|------------|--|-------|---|----------------------------|----|
|  | | | | Applicant(s) Anderson, et al. | | Group Art Unit Unknown 2818 | | |
| Filing Date 8/30/04 | | | | | | | | |
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| | REF | DOCUMENT NUMBER | DATE | COUNTRY | CLASS | SUBCLASS | Translation | |
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| EXAMINER | | | | DATE CONSIDERED | | | | |
| HOANG-QUAN HO | | | | 9/15/05 | | | | |
| EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. | | | | | | | | |